

Edge4717D Quad Channel, Per Pin Precision Measurement Unit

TEST AND MEASUREMENT PRODUCTS

Description

The Edge4717D is a precision measurement unit designed for automated test equipment and instrumentation. Manufactured in a wide voltage CMOS process, it is a monolithic solution for a guad channel per pin PMU.

Each channel of the Edge4717D features a PMU that can force or measure voltage over a typical 15V I/O range, and supports 4 current ranges: \pm 3.2 μ A, \pm 80 μ A, \pm 2 mA, \pm 30 mA.

The Edge4717D has an on-board window comparator per channel that provides two bits of information — DUT too high and DUT too low. There is also a monitor pin which provides a real time analog signal proportional to either the voltage or current measured at the DUT.

The Edge4717D is designed to be a low power, low cost, small footprint solution to allow high pin count testers to support a PMU per pin.

On-board voltage clamps, with over-current detection, provide protection to the DUT and 4717D.

The Edge4717D also has a sample-and-hold feature available for capturing DUT current or voltage measurements.

The Edge4717D is a design improvement to the Edge4717 that features:

- Increased FV/MV range
- Improved over-current detection circuit functionality
- LVTTL comparator outputs (pull-up resistors no longer required)
- Improved HiZ switching characteristics
- Improved Force Voltage Linearity

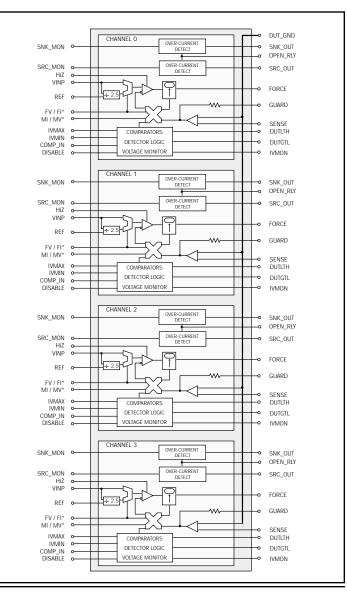
Applications

- Automated Test Equipment
 - Memory Testers
 - VLSI Testers
 - Mixed Signal Tester

Features

- FV / MI Capability
- FI / MV Capability
- FV / MV Capability
- FI / MI Capability
- 4 Current Ranges (± 3.2 μA, ± 80 μA, ± 2 mA, ± 30 mA)
- –5.5V to 9.5V Nominal Output Range (Zero Current)
- -3.5 to 7.5V Nominal Output Range (Full Scale Current)
- On-board Voltage Clamps
- Internal Sample and Hold
- 228 Pin 23 mm x 23 mm TBGA Package

Functional Block Diagram





PIN Description

Pin Name	Pin #	Description
VINP[0:3]	B19, H22, N21, V22	Analog voltage input which forces the output voltage (FV mode) and the output current (FI mode) (one per channel).
REF[0:3]	A19, G22, M21, U22	Reference pin for divide by 2.5 circuit for force current mode; this reference is typically set to 2.25V.
FORCE[0:3]	E2, J2, N2, U2	Analog output pin which forces current or voltage.
SENSE[0:3]	E3, J3, N3, U3	Analog input pin which senses voltage.
FV_FI*[0:3]	A7, C11, A14, B17	TTL compatible input which determines whether the PMU is forcing current or forcing voltage.
MI_MV*[0:3]	C9, B11, B14, C16	TTL compatible input which determines whether the PMU is measuring current or measuring voltage.
RS0[0:3]	C7, B9, C12, B15	TTL compatible current range select inputs.
RS1[0:3]	C6, A8, B12, A15	TTL compatible current range select inputs.
IVMIN[0:3]	C17, H20, M20, U21	Analog input voltages which establish the lower threshold level for the measurement comparator.
IVMAX[0:3]	C18, H21, N22, U20	Analog input voltages which establish the upper threshold level for the measurement comparator.
COMP_IN[0:3]	D2, H2, M2, T2	Analog voltage input to measurement comparator.
DUT_LTH[0:3]	AA13, Y12, AA10, Y9	Digital comparator output that indicates the DUT measurement is less than the upper threshold.
DUT_GTL[0:3]	AA14, AA12, Y11, AA9	Digital comparator output that indicates the DUT measurement is greater than the lower threshold.
DISABLE[0:3]	A6, B10, B13, B16	TTL compatible input which places IVMON output in high impedance.
HIZ[0:3]	B7, A10, C13, A17	TTL compatible input that places the FORCE output into high impedance.
RA[0:3]	F3, K3, P3, V3	External resistor input corresponding to Range A.
RB[0:3]	F2, K2, P2, V2	External resistor input corresponding to Range B.
RC[0:3]	F1, K1, P1, V1	External resistor input corresponding to Range C.
RD[0:3]	G3, L3, R3, W3	External resistor input corresponding to Range D.
SNK_MON[0:3]	F21, K22, R22, AA17	Analog voltage input to sink current clamp.
SRC_MON[0:3]	F22, L22, T22, Y16	Analog voltage input to source current clamp.
SNK_OUT[0:3]	C1, G1, L1, R1	Clamp output.
SRC_OUT[0:3]	E1, J1, N1, U1	Clamp output.



PIN Description (continued)

Pin Name	Pin #	Description			
OPEN_RLY[0:3]	Y14, Y13, AA11, Y10	Open drain output that is used for opening relays between tester and DUT in case of an over-current condition.			
IVMON[0:3]	B18, G21, M22, T21	Analog voltage output that provides a real time monitor of either the measured voltage or measured current level.			
LTCH_MODE[0:3]	B6, C10, A12, A16	Controls a mux for determination of whether IVMONITOR is from sample-and-hold or not sampled.			
SAMPLE[0:3]	C8, A9, A13, C15	Used for sampling the voltage on the SENSE[0:3] voltage monitor pins.			
GUARD[0:3]	D1, H1, M1, T1	Driven guard pin used for guard traces.			
TEST[0:3]	B8, A11, C14, A18	Digital input control pin for mux for testing sample-and-hold.			
TEST_IN[0:3]	C19, J22, N20, V21	Analog input for testing the sample-and-hold.			
COMP1[0:3] COMP2[0:3]	D20, J20, P21, V20 D21, J21, P20, Y19	Internal compensation pins that require an external capacitor connection between the two pins.			
COMP3[0:3]	E21, K21, R21, Y18	Internal compensation pin that requires an external capacitor connection between the pin and ground.			
COMP4[0:3]	F20, K20, R20, Y17	Internal compensation pin that requires an external capacitor connection between the pin and FORCE output.			
DUT_GND	Y6	Input reference pin that should be connected to DUT ground line.			
Power Pins					
VCC	A1, A2, A21, A22, B1, B2, B21, B22, C3, C20, Y3, Y20, AA1, AA2, AA21, AA22, AB1, AB2, AB21, AB22	Positive analog power supply.			
VDD	Y15	Positive digital supply (comparator).			
VEE	A20, B20, C21, C22, D22, E22, G2, L2, R2, W2, W21, W22, Y21, Y22, AA15, AA18, AA19, AA20, AB13, AB14, AB15, AB16, AB17, AB18, AB19, AB20	Negative analog power supply.			
GND	A3, A4, A5, B3, B4, B5, C2, C4, C5, W1, Y1, Y2, Y4, Y5, Y7, Y8, AA3, AA4, AA5, AA6, AA7, AA8, AB3, AB4, AB5, AB6, AB7, AB8, AB9, AB10, AB11, AB12	Ground.			
NC	D3, E20, H3, G20, L20, L21, M3, P22, T3, T20, W20, AA16	No Connection. (Unused pins; leave unconnected).			



PIN Description (continued)

A1 Ball Pad Indicator

Top View

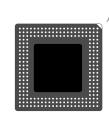
23mm x 23mm 228 Pin TBGA



	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22
Α	A1 VCC	A2 VCC	(A3)	(A4)	(A5)	A6 DISABLEO	A7 FV_FINO	(A8) RS11	A9 SAMPLE1	(A10) HIZ1	(A11) TEST1	(A12) LTCH_MODE2	A13) SAMPLE2	(A14) FV_FIN2	A15)	A16) LTCH_MODE3	A17 HIZ3	(A18) TEST3	A19 IREFO	(A20) VEE	A21 VCC	A22 VCC
В	B1 VCC	B2 VCC	B3 GND	B4 GND	B5 GND	B6 LTCH_MODEO	B7	(B8) TESTO	B9 RS01	B10 DISABLE1	B11) MI_MVN1	B12) RS12	B13) DISABLE2	B14) MLMVN2	B15)	B16) DISABLE3	B17 FV_FIN3	B18 IVMONO	B19 VINPO	B20 VEE	B21)	B22 VCC
С	C1 SNK_OUTO	C2 GND	C3 VCC	C4 GND	C5 GND	C6 RS10	C7 RS00	C8 SAMPLEO	C9 MI_MVN0	C10 LTCH_MODE1	C11) FV_FIN1	C12 RS02	C13)	C14 TEST2	C15 SAMPLE3	C16 MI_MVN3	C17 IV_MINO	C18 IV_MAXO	C19 TEST_INO	C2O VCC	C21 VEE	C22 VEE
D	D1 GUARDO	D2 COMP_INO	D3 NC	D4					D9					D14					D19	D20 COMP10	D21 COMP20	D22 VEE
Е	E1 SRC_OUTO	E2 FORCEO	E3 SENSEO	E4			E7		E9	E10				E14	E15				E19	E20 NC	E21 COMP30	E22 VEE
F	F1 RCO	F2 RBO	F3 RAD	F4					F9					F14		F16			F19	F20 COMP40	F21 SNK_MONO	F22 SRC_MONO
G	G1 SNK_OUT1	G2 VEE	G3 RD0	G4					G9					G14					G19	G20 HLD CAPO (NC)	G21 IVMON1	G22 IREF1
Н	H1 GUARD1	H2 COMP_IN1	H3 NC	Н4					Н9					H14					H19	H20 IV_MIN1	H21)	H22 VINP1
J	J1 SRC_OUT1	J2 FORCE1	J3 SENSE1	J4		J6			J9					J14					J19	J20 COMP11	J21 COMP21	J22 TEST_IN1
K	K1 RC1	K2 RB1	K3 RA1	K4	K5	К6	K7	K8	K9	K10	K11	K12	K13	K14	K15	K16	K17	K18	K19	(K20) COMP41	K21 COMP31	K22 SNK_MON1
L	L1 SNK_OUT2	L2 VEE	L3 RD1	L4		L6			L9					L14					L19	L20 NC	L21 HLD_CAP1 (NC)	L22 SRC_MON1
Μ	M1) GUARD2	M2 COMP_IN2	M3 NC	M4			M7		M9					M14	M15				M19	M20 IV_MIN2	M21)	M22 IVMON2
N	N1 SRC_OUT2	N2 FORCE2	N3 SENSE2	N4			N7		N9	N10	N11		N13	N14	N15				N19	N20 TEST_IN2	N21 VINP2	N22 IV_MAX2
Р	P1 RC2	P2 RB2	P3 RA2	P4					P9					P14		P16			P19	P20 COMP22	P21 COMP12	P22 NC
R	R1 SNK_OUT3	R2 VEE	R3 RD2	R4	R5		R7		R9	R10	R11	R12	R13	R14	R15	R16	R17	R18	R19	R20 COMP42	R21) COMP32	R22) SNK_MON2
Т	T1)	T2 COMP_IN3	T3 NC	T4					Т9					T14					T19	T20 HLD_CAP2 (NC)	T21)	T22 SRC_MON2
U	U1) SRC_OUT3	U2 FORCE3	U3 SENSE3	U4					U9					U14					U19	U20 IV_MAX3	U21) IV_MIN3	U22 IREF3
V	V1 RC3	V2 RB3	V3 RA3	V4			V7		V9	V10	V11	V12	V13	V14	V15	V16	V17	V18	V19	V20) COMP13	V21) TEST_IN3	V22 VINP3
W	W1 GND	W2 VEE	W3 RD3	W4					W9					W14					W19	W20) NC	W21) VEE	W22 VEE
Υ	Y1 GND	Y2 GND	Y3 VCC	Y4 GND	Y5 GND	Y6 DUT_GND	(Y7) GND	(Y8)	Y9 DUT_LITH3	Y10 OPEN_RLY3	Y11) DUT_GTL2	Y12) DUT_LTH1	Y13) OPEN_RLY1	Y14 OPEN_RLYO	Y15) VDD	(Y16) SRC_MON3	(Y17) COMP43	Y18 COMP33	(Y19) COMP23	Y20 VCC	Y21) VEE	Y22 VEE
AA	(AA1)	(AA2)	(AA3)	(AA4)	(AA5) GND	(AA6)	(AA7)	(AA8)	AA9 DUT_GTL3	(AA10) DUT_LTH2	(AA11) OPEN_RLY2	AA12) DUT_GTL1	(AA13)	AA14)	(AA15) VEE	(NC)	(A17) SNK_MON3	(AA18) VEE	(AA19) VEE	(AA20) VEE	(AA21)	(AA22) VCC
AB	AB1)	(AB2)	(AB3)	(AB4)	(AB5)	(AB6)	(AB7)	(AB8)	(AB9)	(AB10) GND	(AB11)	(AB12)	(AB13) VEE	(AB14) VEE	AB15) VEE	(AB16) VEE	(AB17) VEE	AB18) VEE	AB19) VEE	AB20 VEE	AB21)	(AB22) VCC



PIN Description (continued)



A1 Ball Pad Indicator (see gold triangle located at the corner)

Bottom View

23mm x 23mm 228 Pin TBGA

22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	
A22 VCC	(A21) VCC	(A20) VEE	A19 IREFO	(A18) TEST3	A17 HIZ3	(A16) LTCH_MODE3	(A15) RS13	(A14) FV_FIN2	A13) SAMPLE2	A12 LTCH_MODE2	(A11) TEST1	(A10) HIZ1	A9 SAMPLE1	A8 RS11	A7 FV_FINO	A6 DISABLEO	(A5)	(A4)	(A3) GND	A2 VCC	A1 VCC	Α
B22 VCC	B21) vcc	B20 VEE	B19 VINPO	B18 IVMONITORO	B17 FV_FIN3	B16 DISABLE3	B15) RS03	B14 MLMVN2	B13 DISABLE2	B12 RS12	B11) MLMVN1	B10 DISABLE1	B9 RS01	(B8) TESTO	B7 HIZO	B6 LTCH_MODEO	B5 GND	B4 GND	B3 GND	B2 vcc	B1)	В
C22 VEE	C21 VEE	C2O VCC	C19 TEST_INO	C18 IV_MAXO	C17 IV_MINO	C16 MLMVN3	C15 SAMPLE3	C14 TEST2	C13 HIZ2	C12 RS02	C11 FV_FIN1	C10 LTCH_MODE1	C9 MI_MVNO	C8 SAMPLEO	C7 RS00	(C6) RS10	C5 GND	C4 GND	C3 VCC	C2 GND	C1 SNK_OUTO	С
D22 VEE	D21 COMP20	D20 COMP10	D19					D14					D9					D4	D3 NC	D2 COMP_INO	D1 GUARDO	D
E22 VEE	E21 COMP30	E20 NC	E19					E14					E9					E4	E3 SENSEO	E2 FORCEO	E1 SRC_OUTO	Е
F22 SRC_MONO	F21 SNK_MONO	F20 COMP40	F19		F17			F14		F12			F9		F7			F4	F3 RAO	F2 RB0	F1 RCO	F
G22 IREF1	G21 IVMON1	G20 HLD CAPO (NC)	G19					G14					G9					G4	G3 RD0	G2 VEE	G1 SNK_OUT1	G
H22 VINP1	H21 IV_MAX1	H20 IV_MIN1	H19					H14					H9					H4	H3 NC	H2 COMP_IN1	H1 GUARD1	Н
J22 TEST_IN1	J21 COMP21	J20 COMP11	J19					J14					J9					J4	J3 SENSE1	J2 FORCE1	J1 SRC_OUT1	J
K22 SNK_MON1	K21 COMP31	K20 COMP41	K19	K18	K17	K16	K15	K14	K13	K12	K11	K10	K9	K8	K7	K6	K5	K4	K3 RA1	K2 RB1	K1 RC1	K
L22 SRC_MON1	L21 HLD CAP1	L20 NC	L19			L16		L14					L9			L6		L4	L3 RD1	L2 VEE	L1 SNK_OUT2	L
M22 IVMON2	M21 IREF2	M20 IV_MIN2	M19	M18	M17			M14	M13		M11		M9					M4	M3 NC	M2) COMP_IN2	M1) GUARD2	М
N22 IV_MAX2	N21 VINP2	N20 TEST_IN2	N19				N15	N14		N12		N10						N4	N3 SENSE2	N2 FORCE2	N1) SRC_OUT2	N
P22 NC	P21 COMP12	P20 COMP22	P19					P14					P9					P4	P3 RA2	P2 RB2	P1 RC2	Р
R22 SNK_MON2	R21 COMP32	R20 COMP42	R19	R18	R17	R16	R15	R14	R13	R12	R11	R10	R9		R7			R4	R3 RD2	R2 VEE	R1 SNK_OUT3	R
T22) SRC_MON2	T21)	T20 HLD CAP2	T19					T14					Т9					T4	T3 NC	T2 COMP_IN3	T1)	T
U22 IREF3	U21) IV_MIN3	U20 IV_MAX3	U19					U14					U9					U4	U3 SENSE3	U2 FORCE3	U1) SRC_OUT3	U
V22) VINP3	V21) TEST_IN3	V20 COMP13	V19	V18	V17		V15	V14	V13	V12	V11	V10	V9		V7			V4	V3 RA3	V2 RB3	V1)	V
W22 VEE	W21) VEE	W2O NC	W19	W18	W17	W16	W15	W14	W13	W12	W11	W10	W9	W8	W7	W6	W5	W4	W3 RD3	W2 VEE	W1) GND	W
Y22 VEE	Y21 VEE	Y20 VCC	(Y19) COMP23	Y18 COMP33	Y17 COMP43	Y16 SRC_MON3	Y15 VDD	Y14 OPEN_RLYO	Y13 OPEN_RLY1	Y12) DUT_LTH1	Y11) DUT_GTL2	Y10 OPEN_RLY3	V9 DUT_LTH3	Y8 GND	Y7 GND	Y6 DUT_GND	Y5 GND	Y4 GND	Y3 VCC	Y2 GND	Y1) GND	Υ
(AA22) VCC	(AA21) VCC	(AA20) VEE	(AA19) VEE	(AA18) VEE	(A17) SNK_MON3	AA16 HLD CAP3	(AA15) VEE	(AA14) DUT_GTLO	AA13 DUT_LTHO	AA12 DUT_GTL1	(AA11) OPEN_RLY2	AA10 DUT_LTH2	AA9) DUT_GTL3	(AA8)	(AA7)	(AA6) GND	(AA5)	(AA4)	(AA3)	(AA2) VCC	(AA1)	AA
(AB22) VCC	(AB21)	(AB20) VEE	(AB19) VEE	(AB18) VEE	(B17) VEE	(AB16) VEE	(AB15) VEE	(AB14) VEE	(AB13) VEE	AB12 GND	(AB11)	AB10) GND	(AB9)	(AB8)	(AB7)	(AB6)	(AB5)	(AB4)	(AB3)	(AB2)	(AB1)	AB



Circuit Description

Circuit Overview

The Edge4717D is a quad channel parametric test and measurement unit that can :

- Force Voltage / Measure Current
- Force Current / Measure Voltage
- Force Voltage / Measure Voltage
- Force Current / Measure Current
- Measure Voltage / Force Disable

The Edge4717D features a PMU (per channel) that can force or measure voltage over a 15V range and force or measure current over four distinct ranges:

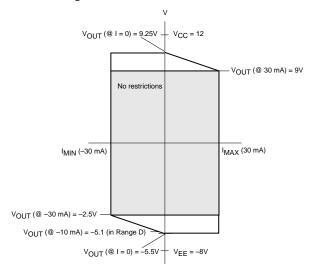
- $\pm 3.2 \,\mu\text{A}$
- $\pm 80 \mu A$
- ± 2 mA
- ± 30 mA

The Edge4717D features an on-board window comparator (per channel) that provides two bit measurement range classification.

Also, a monitor pin, IVMON, is capable of outputting either a real time analog voltage signal which tracks the measured parameter, or a sampled value of the measurement parameter captured using the sample and hold circuitry.

PMU Functionality

The trapezoid in Figure 1 describes the current-voltage functionality of the PMU with VCC = 12V and VEE = -8V, in Range D.



NOTE: Negative current is defined as current flowing into PMU from DUT.

Figure 1. PMU Functionality

Control Inputs

FV / FI* is a TTL compatible input which determines whether the PMU forces current or voltage, and MI/MV* is a TTL compatible input which determines whether the PMU measures current or voltage. FV/FI* and MI/MV* are independent for each channel of the Edge4717D. HIZ is a TTL compatible input which can be used to place the PMU's force amp into a high impedance state. Tables 1 and 2 describe the modes of operation related to these three input pins.

HIZ	FV / FI*	MI/MV*	Mode of Operation			
1	Х	Х	High Impedance			
0	0	0	Force Current, Measure Voltage			
0	0	1	Force Current, Measure Current			
0	1	0	Force Voltage, Measure Voltage			
0	1	1	Force Voltage, Measure Current			

Table 1.

RSO and RS1 are TTL compatible inputs to an internal analog MUX which selects an external resistor corresponding to a desired current range. The truth table for RSO and RS1, along with the associated external resistor values and current ranges, is shown in Table 2. RSO and RS1 are independent for each channel of the Edge4717D.

RS1	RS0	Range	Current Range	"Nominal" Ext. R
0	0	А	3.2 µA	$RA = 625K\Omega$
0	1	В	80 μΑ	$RB = 25K\Omega$
1	0	С	2 mA	$RC = 1K\Omega$
1	1	D	30 mA	$RD = 40\Omega$

Table 2.



Circuit Description (continued)

FORCE/SENSE

FORCE is an analog output which either forces a current or forces a voltage, depending on which operating mode is selected. In FV mode, the voltage forced is equivalent to the voltage applied to the VINP pin. In FI mode, the current forced is mapped to the input as described in the Force Current section. FORCE can be placed in a high-impedance state through the setting of the HIZ input pin.

When the HIZ input pin is set to logical "O", the Edge4717D FORCE output will be controlled by the internal driver amplifier, and the Edge4717D will force a user-defined current or voltage (depending upon the setting of FV/FI*) at the FORCE pin. When HIZ is set to logical "1", the FORCE output is placed into a low-leakage, high impedance state.

SENSE is a high impedance analog input which measures the DUT voltage in the MV operating mode.

(FORCE and SENSE are brought out to separate pins to allow remote sensing.)

IVMON

IVMON is a real time analog voltage output which tracks the sensed parameter.

In the MV mode (MI/MV * = 0), the output voltage displayed at IVMON is a 1:1 mapping of the SENSE voltage. In the MI mode (MI/MV * = 1), IVMON follows the equation:

IVMON = I(measured) * REXT

Using nominal values for the external resistors (RA, RB, and RC), a voltage at IVMON of +2V corresponds to Imax, and -2V corresponds to Imin of the selected current range. For Range D, +1.2V corresponds to Imax and -1.2V corresponds to Imin.

The IVMON pin can also be placed into a high impedance state by using the DISABLE input (see Table 3).

Disable	MI / MV*	Sensed Parameter
1	Х	High Impedance
0	0	Measured Voltage
0	1	Measured Current

Table 3.

Sample and Hold

The Edge4717D features a sample and hold circuit (per channel) which can be used to capture the corresponding voltage value of the sensed parameter (MI or MV) to be displayed at IVMON.

The output of the sample and hold is internally connected to IVMON through a latch controlled by LTCH_MODE. The setting of LTCH_MODE determines whether the data at IVMON comes from the sample and hold circuit or directly from the sensed parameter (see Table 4).

LTCH_MODE	Sample	Sample-and_Hold State		
0	Х	Transparent		
1	▼ (Falling Edge)	Sample Data		
1	0	Hold Data		
1	1	Transparent		

Table 4.

Note: No update is performed on the sample-and-hold.

Sample and Hold Testing

An analog MUX in the 4717D allows for testing of the sample-and-hold circuit.

The MUX control pin, TEST, is a TTL compatible input whose operation is described in Table 5. To test the sample and hold circuitry, an analog signal can be applied to the TEST IN pin and sampled.



Circuit Description (continued)

TEST	Function
0	Normal Operation
1	TEST_IN used for sample- and-hold testing

Table 5.

Test Head Ground Reference

The Edge4717D features a test head ground referencing feature which allows the force voltage function to be referenced to a separate ground reference other than the ground (GND) power used for the device. The test head ground should be connected to the DUT_GND pin of the Edge4717D. The maximum allowed variation between DUT_GND and GND is \pm 250 mV.

Force Voltage Mode

In the FV mode (FV/FI * = 1), VINP is a high impedance, analog voltage input that maps directly to the voltage forced at the FORCE pin.

Measure Current Mode

In the MI mode (MI/MV * = 1), a current monitor is connected in series with the PMU forcing amplifier. This monitor generates a voltage that is proportional to the current passing through it, and is brought out to IVMON. This voltage (corresponding to the measured current) can also be tested by the on-board window comparator.

Force Current Mode

In the FI mode ($FV/FI^* = 0$), VINP is a high impedance, analog voltage input that is converted into a current at the FORCE pin (see Figure 1) using the following relationship:

Forced Current =
$$\frac{\text{VINP} - \text{VREF}}{(\text{REXT} * 2.5)}$$

where VREF is the reference voltage input at the REF pin which is nominally set at 2.25V. (Positive current is defined as current flowing out of the PMU.) Table 6 describes the relationship between the voltage applied to VINP and the current at FORCE for Ranges A, B, and C.

VINP	Corresponding Forced Current
VREF + 5.5V	≥ Imax (Full-Scale, Ranges A, B, C)
VREF + 3.5V	≥ Imax (Full-Scale, Range D)
VREF	0
VREF – 3.5V	≤ Imin (Full-Scale, Range D)
VREF – 5.5V	≤ Imin (Full-Scale, Ranges A, B, C)

Table 6.

In the Force Current mode, the voltage at VINP is divided by 2.5 internally on the chip, so that $a \pm 2V$ range is used internally for forcing currents on Ranges A, B, and C. Range D uses $a \pm 1.2V$ range across REXT for forcing currents.

Measure Voltage Mode

In the MV mode (MI/MV * = 0), DUT voltage is measured via the SENSE input pin. This measured voltage can be displayed on the IVMON pin and tested using the internal window comparator.

Comparator

The Edge4717D features an on-board window comparator which provides two-bit measurement range classification. IVMAX and IVMIN are high impedance analog inputs that establish the upper and lower thresholds for the window comparator. COMP_IN is the window comparator input pin. COMP_IN should be connected to IVMON on each channel if it is desired to use the comparator to indicate PMU measurements.

In the MI mode, an I/V MAX input of +2V will set the upper threshold of the window comparator to a voltage corresponding to +FSC (full-scale current), and an I/V MIN input of -2V will set the lower threshold to a voltage corresponding to -FSC for Ranges A, B, and C. Similarly for Range D, -1.2V corresponds to sinking full-scale current, and +1.2V corresponds to sourcing full-scale current (positive current is defined as current flowing out of the PMU).

DUTGTL the DUTLTH are LVTTL compatible outputs which indicate the range of the measured parameter in relation to IVMIN and IVMAX. Comparator functionality is summarized in Table 7.



Circuit Description (continued)

TEST CONDITION	DUT LTH	DUT GTL
COMP_IN > IVMAX COMP_IN < IVMAX	0 1	N/A
COMP_IN > IVMIN COMP_IN < IVMIN	N/A	1 0
COMP_IN < IVMAX and COMP_IN > IVMIN	1	1

Table 7. Comparator Truth Table

REXT Selection

The Edge4717D is designed such that the maximum voltage drop across REXT (RA, RB, RC, or RD depending on range selected using RSO and RS1 inputs) is $\leq 2V$.

Resistor values can be chosen to operate the PMU at any current range up to $\pm\,50\,$ mA in accordance with the following equation:

$$\label{eq:REXT} \begin{split} \text{REXT}[\Omega] = & \ \frac{2 \ [\text{V}]}{\text{IMAX}[\text{A}]} \ , \ \text{IMAX} \leq \ 50 \ \text{mA} \ \text{for Range D} \\ & \ \text{IMAX} \leq \ 2 \ \text{mA} \ \text{for Range C} \\ & \ \text{IMAX} \leq \ 80 \ \mu \text{A} \ \text{for Range B} \\ & \ \text{IMAX} \leq \ 3.2 \ \text{mA} \ \text{for Range A} \end{split}$$

Voltage Clamps/Over-Current Detection

The Edge4717D features four pairs of on-board clamps (one pair per channel), which can be used to clamp the voltage of pins connected to SRC OUT and SNK OUT between limits set by the voltages applied to SRC MON and SNK_MON. SNK_MON is a high impedance input that establishes the upper clamping limit, while SRC_MON is a high impedance analog input that establishes the lower clamping limit. In addition to voltage clamping functionality, the clamp circuitry of the Edge4717D also features overcurrent detection capability. Over-current detection is only enabled when one of the voltage clamping thresholds is exceeded (FORCE + V_{diode} > SNK_MON or FORCE -Vdiode < SRC_MON). When enabled, an over-current condition is signaled via the OPEN-RLY pin. OPEN_RLY is an open drain output pin that pulls down when an overcurrent condition is detected. OPEN_RLY functionality is depicted in Table 8.

Clamp Condition	Clamp Diode Current	OPEN_RLY
SRC_OUT < FORCE-V _{diode}	N/A	1
SRC_OUT > FORCE-V _{diode}	I _{CLAMP} > 55 mA I _{CLAMP} < 55 mA	0 1
SNK_OUT < FORCE+V _{diode}	I _{CLAMP} > 55 mA I _{CLAMP} < 55 mA	0 1
SNK_OUT > FORCE+V _{diode}	N/A	1

Table 8. Over-Current Detection Circuit Functionality (V_{diode} is the forward voltage of the external clamp diode).

For applications that require the use of external resistors that are much smaller in Ohmic value than those that are outlined in Table 2, one will need to account for the variation in switch resistance vs. common mode voltage of the range selection switches (A-D in Figure 3) when specifying the overall accuracy of the application.

Common Mode Error/Calibration

In order to attain a high degree of accuracy in a typical ATE application, offset and gain errors are accounted for through software calibration. When operating the Edge4717D in the Measure Current (MI) or Force Current (FI) modes, an additional source of error, common mode error, should be accounted for. Common mode error is a measure of how the common mode voltage, V_{CM} , at the input of the current sense amplifier affects the forced or measured current values (see Figure 2). Since this error is created by internal resistors in the current sense amplifier, it is very linear in nature.

Using the common mode error and common mode linearity specifications, one can see that with a small number of calibration steps (see Applications note PMU-A1), the effect of this error can be significantly reduced.



Circuit Description (continued)

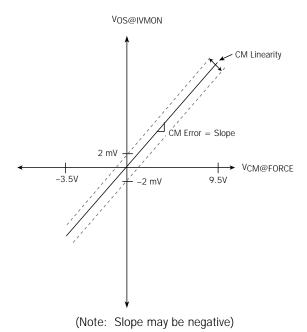


Figure 2. Graphical Representation of

Common Mode Error

Transient Clamps

The Edge4717D has on-board transient clamps to limit the voltage and current spikes that might result from either changing the current range or changing the operating mode.

Driven Guard Pin

The Edge4717D features a pin (per channel), GUARD, which can be used to drive the guard traces of a FORCE/ SENSE pair. By surrounding FORCE and SENSE traces with guard traces which connect to the GUARD pin, an effective method to achieve minimal leakage can be achieved.

Power Supply Sequencing

In order to avoid the possibility of latch-up, the following power-up requirements must be satisified:

- 1. $VEE \leq GND \leq VDD \leq VCC$ at all times
- 2. $VEE \leq All inputs \leq VCC$

The following power supply sequencing can be used as a guideline when operating the Edge4717D:

Power Up Sequence

- 1. VCC (substrate)
- 2. VEE/VDD
- 3. Digital Inputs
- 4. Analog Inputs

Power Down Sequence

- 1. Analog Inputs
- 2. Digital Inputs
- 3. VEE/VDD
- 4. VCC (substrate)



Circuit Description (continued)

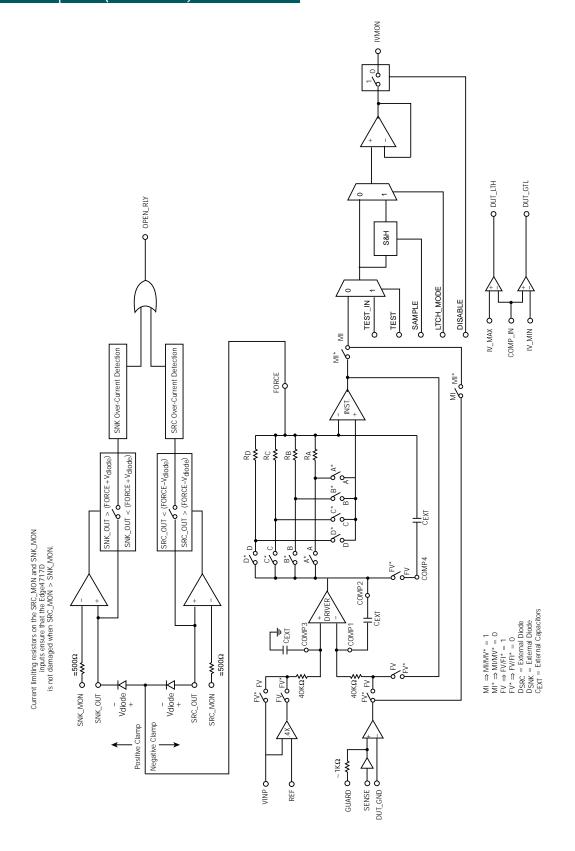
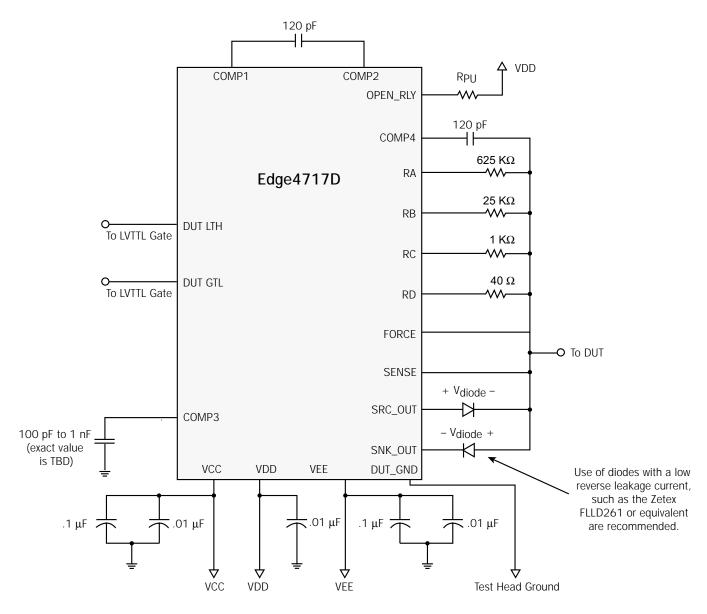


Figure 3. Functional Schematic



Application Information

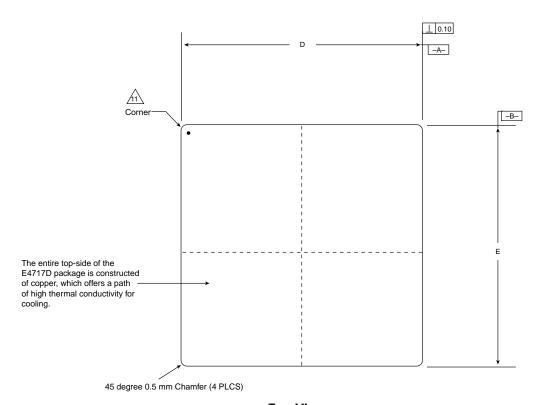


Actual decoupling capacitor values depend on the actual system environment.

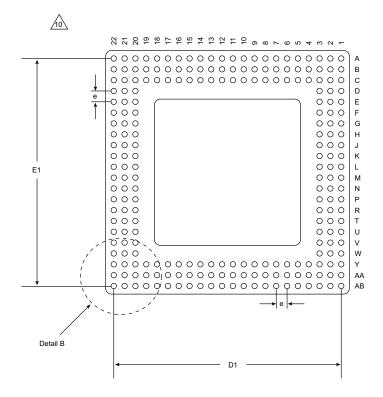
Figure 4. Required External Components (Per Channel)



Package Information



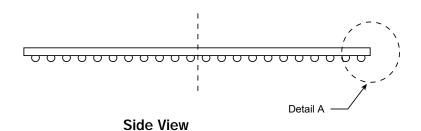
Top View

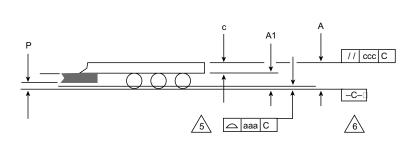


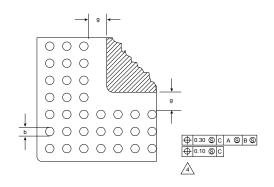
Bottom View



Package Information (continued)







Detail A Detail B

NOTES:

- 1. All dimensions are in millimeters.
- 2. "e" represents the basic solder ball grid pitch.
- 3. "M" represents the basic solder ball matrix size, and symbol "N" is the maximum allowable number of balls after depopulating.



"b" is measured at the maximum solder ball diameter (after reflow) parallel to primary datum $\boxed{-C-}$.



Dimension "aaa" is measured parallel to primary datum _-C_ .



Primary datum —C— and seating plane are defined by the spherical crowns of the solder balls.

- 7. Package surface shall be black oxide.
- 8. Cavity depth varies with die thickness.
- 9. Substrate material base is copper.

 $\frac{1}{2}$

Bilateral tolerance zone is applied to each side of package body. 45 degree 0.5 mm Chamfer corner and white dot for Pin 1 identification.

D	Dimensional References					
REF.	MIN.	MAX.				
А	1.25	1.4	1.55			
A1	0.40	0.50	0.60			
D	22.80	23.00	23.20			
D1		21.00 BSC				
E	22.80	23.00	23.20			
E1	21.00 BSC					
b	0.525	0.65	0.775			
С	0.85	0.90	0.95			
М		22				
Ν		228				
aaa			0.15			
ссс			0.25			
е	1.00 TYP					
g	0.35					
Р	0.15					



Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Units
Positive Analog Power Supply	VCC	11.5	12	12.5	V
Negative Analog Power Supply	VEE	-8.5	-8	-7.5	V
Total Analog Power Supply	VCC – VEE	19	20	21	V
Digital Power Supply	VDD	3.0	3.3	5.25	V
Case Temperature	TC	25		+65	°C
Thermal Resistance of Package (Junction to Case)	θјс		0.3		°C/W

Absolute Maximum Ratings

Parameter	Symbol	Min	Тур	Max	Units
Positive Power Supply	VCC			+15	V
Negative Power Supply	VEE	-15			V
Total Power Supply	VCC – VEE	0		22	V
Digital Power Supply	VDD	0		+ 7	V
Digital Inputs		5		7.0	V
Analog Inputs		VEE – .5		VCC + .5	V
Storage Temperature		-55		+125	°C
Case Temperature				100	°C
Soldering Temperature				260	°C

Stresses above listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



DC Characteristics

Parameter	Symbol	Min	Тур	Max	Units
Power Supplies					
Power Supply Consumption (No-Load) Positive Supply Negative Supply "Digital" Supply	ICC IEE IDD		35 35	72 72 5	mA mA mA
Power Supply Rejection Ratio VCC to any Analog Output (except in Hold mode) 1 MHz 500 kHz 100 kHz	PSRR		20 20 25		dB dB dB
VEE to any Analog Output (except in Hold mode) 1 MHz 500 kHz 100 kHz			16 18 25		dB dB dB
VDD to any Analog Output (except in Hold mode) < 1 MHz			60		dB
VCC to IVMON (Hold Mode) 1 MHz 500 kHz 100 kHz 200 Hz			0.6 6 20 30		dB dB dB dB
VEE to IVMON (Hold Mode) 1 MHz 500 kHz 100 kHz 200 Hz			1.7 7 21 30		dB dB dB dB
VDD to IVMON (Hold Mode) < 1 MHz			60		dB
Force Voltage Mode					
Input Voltage Range Input Leakage Current	VINP Ileak	VEE + 2.0 -1	0	VCC - 2.0 1	V µA
Output Forcing Voltage (Positive Full-Scale Current through R _{EXT})	VFORCE	VEE + 2.5		VCC - 4.5	V
Output Forcing Voltage (O Current through R _{EXT})	VFORCE	VEE + 2.5		VCC - 2.5	V
Output Forcing Voltage (Negative Full-Scale Current through R_{EXT})	VFORCE	VEE + 4.5		VCC - 2.5	V
Voltage Accuracy Offset Gain Linearity	VOS Gain FV INL	-200 .985 -0.025	.01	200 1.015 +0.025	mV V/V % FSVR



DC Characteristics (continued)

Parameter	Symbol	Min	Тур	Max	Units
Measure Current Mode					
Current Measurement Range Range A Range B Range C Range D	^I MEASURE	-3.2 -80 -2 -30		3.2 80 2 30	μΑ μΑ mA mA
Current Measurement Accuracy Offset (@ IVMON) Gain (Note 1) Linearity Ranges A, B, C	VOS Gain MI INL	–150 .985 –.08		150 1.015	mV V/V % FSCR
Range D		-80		+80	μA
Common Mode Error Common Mode Linearity	CM Error	-5.5		5.5	mV/V
FORCE = VEE + 4.5V to VCC - 4.75V IVMON Output Impedance	CM INL Rout	05	500	.05	%FSCR Ω
IVMON Leakage Current (IVMON = VEE+2.5V TO VCC-2.5V)	ILEAK	-100		100	nA
Force Current Mode					
Input Voltage Range Input Leakage Current REF Input Voltage Range REF Leakage Current	VINP Ileak Vref Ileak	VREF - 5.5 -1 0 -1	0	VREF + 5.5 1 2.5 –1	V µA V µA
Output Forcing Current Range A Range B Range C Range D	IFORCE	-3.2 -80 -2 -30		3.2 80 2 30	μΑ μΑ mA mA
Compliance Voltage Range Positive Full-Scale Current O Current Negative Full-Scale Current	VFORCE	VEE + 2.5 VEE + 2.5 VEE + 3.0		VCC - 3.0 VCC - 2.5 VCC - 2.5	V V V
Current Accuracy Offset Gain (Note 2) Linearity	IOS Gain FI INL	-3.6 .385	.4	3.6 .415	% FSCR V/V
Ranges A, B, C Range D	I I IIVL	08 -80		.08 +80	% FSCR µA
Common Mode Error	CM Error	-5.5		5.5	mV/V
Common Mode Linearity FORCE = VEE + 4.5V to VCC - 4.5V	CM INL	05		.05	% FSCR



DC Characteristics (continued)

Parameter	Symbol	Min	Тур	Max	Units
Measure Voltage Mode					
Voltage Measurement Range	VSENSE	VEE + 2.5		VCC - 2.5	V
Voltage Measurement Accuracy Offset Gain Linearity FORCE/SENSE Combined Leakage Current in HiZ (FV/FI*=0, FORCE/SENSE = VEE+2.5V to VCC-2.5V) IVMON Output Impedance IVMON Leakage Current (IVMON = VEE+2.5V to VCC-2.5V)	VOS Gain MV INL I _{LEAK} ROUT I _{LEAK}	-200 .985 025 -10	±.01	200 1.015 .025 10	mV V/V %FSVR nA Ω nA
Digital Inputs (FV/FI*, MI/MV*, RS0, RS1, DISABLE, TEST, HiZ, LTCH_MODE, SAMPLE)					
Input Low Level	VIL			0.8	V
Input High Level	VIH	2.0			V
Input Leakage Current	lleak	-1	0	1	μΑ
Voltage Clamps					
Range	SNK_MON - SRC_MON	.5		16.0	V
Effective Output Impedance of Clamps	Rout			10	Ω
Sink Clamp Voltage Range	SNK_MON	VEE + 2.5		VCC - 2.0	V
Source Clamp Voltage Range	SRC_MON	VEE + 2.0		VCC - 2.5	V
SRC_MON Leakage Current	ILEAK	-1		1	μΑ
SNK_MON Leakage Current	I _{LEAK}	-1		1	μΑ
Linearity @ 5 mA Constant Current	CLAMP INL	400		+.400	% FSVR
Offset @ 5 mA Constant Current	VOS	-150		+150	mV
PPMU Voltage Clamps Current Interrupt Limit (OPEN_RLY Trigger Current)	ICLAMP	35		95	mA
PPMU Voltage Clamps Current Limiting Range	I _{LIMIT}	35		95	mA
Output Low Voltage for OPEN_RLY Pin @ 1 mA	V _{OL}			500	mV
TEST_IN Leakage Current	I _{LEAK}	-1		1	μΑ
OPEN_RLY Leakage Current @ 5V	I _{LEAK}	-1		1	μΑ
Sample and Hold Circuit					
Linearity Error	S&H INL	025	.01	.025	% FSVR
Hold Step	V _{HS}		16	20	mV
TempCo of Hold Step (Note 3)	ΔV / Δ°C			50	μV/°C
Output Impedance of IVMON (Note 3)	Rout		500		Ω



DC Characteristics (continued)

Parameter	Symbol	Min	Тур	Max	Units
Short Circuit Protection					
Forcing Op-Amp Current Limit (Note 3)	I _{MAX}	35		75	mA
Driven Guard / Test Head Ground					
GUARD - SENSE @ DUT_GND = 0 SENSE = 5V	V _{DIFF}	-100		+100	mV
DUT_GND to GND Voltage Range	Vos	-250		+250	mV
DUT_GND Leakage Current	I _{LEAK}	-1		1	μA
Comparator					
IVMAX Voltage Range	IVMAX	VEE + 1.75		VCC - 1.75	V
IVMIN Voltage Range	IVMIN	VEE + 1.75		VCC - 1.75	V
Comparator Offset (IVMIN, IVMAX)	Vos	-100		+100	mV
Input Bias Current at (IVMIN, IVMAX, COMP_IN)	l _{bias}	-1		+1	μΑ
Digital Outputs (DUTLTH, DUTGTL)					
Output Low Level (TBD load)	Vol			400	mV
Output High Level (TBD load)	V _{OH}	2.4		VDD	V

Note 1: Gain = $\frac{IVMON}{V_{EXT}}$, where V_{EXT} is the voltage across R_{EXT} , which corresponds to measured current.

Note 2: Gain = $\frac{V_{EXT}}{VINP - REF}$, REF = 2.25V nominal, V_{EXT} is the voltage across R_{EXT} , which corresponds to forced current.

Note 3: Guaranteed by design and characterization. Not production tested.

Unit Definitions:

FSCR = Full Scale Current Range

Range A, \pm 3.2 μ A

Range B, ± 80 µA

Range C, \pm 2 mA

Range D, ± 30 mA

FSVR = Full Scale Voltage Range

FV mode, no current = 14V minimum

FV mode, current load = 12V minimum

MV mode = 14V minimum



AC Characteristics

Parameter	Symbol	Min	Тур	Max	Units
Force Voltage / Measure Current					
FORCE Output Voltage Settling Time (Note 1) (To 0.1% of 10V step) RANGE A RANGES B, C, D	^t settle			2 300	ms µs
Measured Current Settling Time (Note 1) (To 0.1% of FSCR step) RANGE A RANGES B, C, D	^t settle			4 300	ms µs
Stability (Note 1) Capacitive Loading Range for Stable Operation	C _{LOAD}	0		10	nF
Force Amp Saturation Recovery Time HiZ True to FORCE Disable Time HiZ False to FORCE Enable Time	t _{sr} t _z t _{oe}		25	1 15	µs µs
Force Current / Measure Voltage					
FORCE Output Current Settling Time (Note 1) (To 0.1% of FSCR step) RANGE A RANGES B, C, D	tsettle			4 300	ms µs
SENSE (Measure) Voltage Settling Time (Note 1) (To 0.1% of 10V step) RANGE A RANGES B, C, D	tsettle			4 300	ms µs
Stability (Note 1) Capacitive Loading Range for Stable Operation	C _{LOAD}	0		10	nF
Force Amp Saturation Recovery Time HiZ True to FORCE Disable Time HiZ False to FORCE Enable Time	t _{sr} t _z t _{oe}		25	1 15	µs µs
I/V Monitor					
Enable Time	toe			500	ns
Disable Time	t _z			500	ns



AC Characteristics (continued)

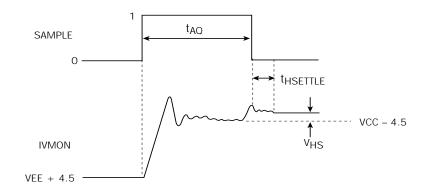
Parameter	Symbol	Min	Тур	Max	Units
Sample and Hold Circuit					
Droop Rate	ΔV/Δt			40	mV/s
Acquisition Time (to 0.025% of Sampled Value)	t _{AQ}		1	10	μs
Hold Mode Settling Time (Notes 1, 2) Measure Voltage Mode To 0.1% of 10V Step To 0.025% of 10V Step	th settle		0.8 1.4	1.5 2	μs μs
Measure Current Mode (Notes 1, 2) To 0.1% of 4V Step To 0.025% of 4V Step	thsettle		1.3 1.8	2 3	μs μsf
Comparators					
Propagation Delay	tpd			25	μs

AC Test Conditions: COMP3 = 120 pF to Ground; COMP4 = 120 pF to FORCE; Capacitor between COMP1

COMP2 = 120 pF; Load at FORCE/SENSE combined output = 100 pF.

Note 1: Guaranteed by design and characterization. Not production tested.

Note 2: Sample and Hold Circuit Acquisition Time (t_{AQ}) and Settling Time $(t_{HSETTLE})$ are described below:



CONDITIONS:

 $LTCH_MODE = 1$ IVMON = 100 pF to GND



Ordering Information

Model Number	Package
E4717DBG	228 Pin 23 mm x 23 mm TBGA
EVM4717DBG	Edge4717D Evaluation Board



This device is ESD sensitive. Care should be taken when handling and installing this device to avoid damaging it.

Contact Information

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Test and Measurement Division
10021 Willow Creek Rd., San Diego, CA 92131
Phone: (858)695-1808 FAX (858)695-2633